

SAR TEST REPORT

No. I17Z62077-SEM01

For

TCL Communication Ltd.

LTE/UMTS/GSM Smartphone

Model Name: 5058A

With

Hardware Version: PIO

Software Version: V1.0

FCC ID: 2ACCJB099

Issued Date: 2018-1-18



Note:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description
I17Z62077-SEM01	Rev.0	2018-1-18	Initial creation of test report



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1 Test Laboratory

1.1 Testing Location

Company Name:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25 °C,
Relative humidity:	30%~ 70%
Ground system resistance:	< 0.5 Ω
Ambient noise & Reflection:	< 0.012 W/kg

1.3 Project Data

Project Leader:	Qi Dianyuan	
Test Engineer:	Lin Xiaojun	
Testing Start Date:	December 25, 2017	
Testing End Date:	December 30, 2017	

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

路城村

Deputy Director of the laboratory

(Approved this test report)



2 Statement of Compliance

The maximum results of SAR found during testing for TCL Communication Ltd. LTE/UMTS/GSM Smartphone 5058A is as follows:

Table 2.1: Highest Reported SAR (1g)

Table 2.11 Highest Reported CAR (19)				
Exposure Configuration	Technology Band	Highest Reported SAR 1g (W/Kg)	Equipment Class	
	GSM 850	0.21		
	PCS 1900	0.16		
	UMTS FDD 2	0.31		
	UMTS FDD 4	0.41		
	UMTS FDD 5	0.36	505	
Head	LTE Band 2	0.35	PCE	
(Separation Distance 0mm)	LTE Band 4	0.39		
	LTE Band 5	0.21		
	LTE Band 7	0.17		
	LTE Band 12	0.26		
	LTE Band 13	0.23		
	WLAN 2.4 GHz	0.33	DTS	
	GSM 850	0.36		
	PCS 1900	0.58		
	UMTS FDD 2	0.67		
	UMTS FDD 4	0.90		
l latan at	UMTS FDD 5	0.44	PCE	
Hotspot (Separation Distance 10mm)	LTE Band 2	0.61	PCE	
	LTE Band 4	0.61		
	LTE Band 5	0.25		
	LTE Band 7	0.61		
	LTE Band 12	0.32		
	LTE Band 13	0.37		
	WLAN 2.4 GHz	0.09	DTS	

The SAR values found for the Mobile Phone are below the maximum recommended levels of 1.6 W/Kg as averaged over any 1g tissue according to the ANSI C95.1-1992.

For body worn operation, this device has been tested and meets FCC RF exposure guidelines when used with any accessory that contains no metal and which provides a minimum separation distance of 10 mm between this device and the body of the user. Use of other accessories may not ensure compliance with FCC RF exposure guidelines.

The EUT battery must be fully charged and checked periodically during the test to ascertain uniform power output.

The measurement together with the test system set-up is described in annex C of this test report. A detailed description of the equipment under test can be found in chapter 4 of this test report.

The highest reported SAR value is obtained at the case of (Table 2.1), and the values are: 0.90 W/kg



(1g).

Table 2.2: The sum of reported SAR values for main antenna and WiFi

	Position	Main antenna	WiFi	Sum
Highest reported				
SAR value for	Left hand, Touch cheek	0.41	0.33	0.74
Head				
Highest reported				
SAR value for	Rear	0.90	0.09	0.99
Body				

Table 2.3: The sum of reported SAR values for main antenna and BT

	Position	Main antenna	ВТ	Sum
Maximum reported	Loft hand. Touch shock	0.41	0.10	0.60
SAR value for Head	Left hand, Touch cheek	0.41	0.19	0.60
Maximum reported	Deer	0.00	0.00	0.00
SAR value for Body	Rear	0.90	0.09	0.99

^{[1] -} Estimated SAR for Bluetooth (see the table 13.3)

According to the above tables, the highest sum of reported SAR values is 0.99 **W/kg (1g)**. The detail for simultaneous transmission consideration is described in chapter 13.



3 Client Information

3.1 Applicant Information

Company Name:	TCL Communication Ltd.
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City:	Shanghai
Postal Code:	201203
Country:	China
Contact Person:	Gong Zhizhou
E-mail:	zhizhou.gong@tcl.com
Telephone:	0086-21-31363544
Fax:	0086-21-61460602



4 Equipment Under Test (EUT) and Ancillary Equipment (AE)

4.1 About EUT

Description:	LTE/UMTS/GSM Smartphone	
Model name:	5058A	
Operating mode(a):	GSM 850/900/1800/1900 WCDMA850/900/1700/1900/2100	
Operating mode(s):	LTE B1/2/3/4/5/7/8/12/13/17/28, BT, WLAN	
	825 – 848.8 MHz (GSM 850)	
	1850.2 – 1910 MHz (GSM 1900)	
	826.4-846.6 MHz (WCDMA 850 Band V)	
	1712.4 – 1752.6 MHz (WCDMA 1700 Band IV)	
	1852.4–1907.6 MHz (WCDMA1900 Band II)	
Tooted Ty Fraguency	1860 – 1900 MHz (LTE Band 2)	
Tested Tx Frequency:	1720 – 1745 MHz (LTE Band 4)	
	824.7 – 848.3 MHz (LTE Band 5)	
	2502.5 – 2567.5 MHz (LTE Band 7)	
	699.7 – 715.3 MHz (LTE Band 12)	
	779.5 –784.5 MHz (LTE Band 13)	
	2412 – 2462 MHz (Wi-Fi 2.4G)	
GPRS/EGPRS Multislot Class:	12	
GPRS capability Class:	В	
Test device Production information:	Production unit	
Device type:	Portable device	
Antenna type:	Integrated antenna	
Accessories/Body-worn configurations:	Headset	
Hotspot mode:	Support	
Product Dimension:	L: 152.5mm W: 71.2mm overall diagonal: 168.3mm	

4.2 Internal Identification of EUT used during the test

EUT								
EUTID	IMEI	HW Version	SW Version					
1	015097000000603	PIO	V1.0					
2	015097000000702	PIO	V1.0					
3	015097000000686	PIO	V1.0					

^{*}EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test SAR with the EUT1&2 and conducted power with the EUT3.

4.3 Internal Identification of AE used during the test

AE ID	Description	Model	SN	Manufactor	
AE1	Battery	Li-Polymer	CAC2900009C7	VEKEN	
AE2	Battery	Li-Polymer	CAC2900007C1	BYD	
AE3	Headset	CCB0046A10C4	1	MEIHAO	
AE4	Headset	CCB0046A10C6	1	SHENGHUA	

^{*}AE ID: is used to identify the test sample in the lab internally.



5 TEST METHODOLOGY

5.1 Applicable Limit Regulations

ANSI C95.1–1992: IEEE Standard for Safety Levels with Respect to Human Exposure to Radio Frequency Electromagnetic Fields, 3 kHz to 300 GHz.

It specifies the maximum exposure limit of **1.6 W/kg** as averaged over any 1 gram of tissue for portable devices being used within 20 cm of the user in the uncontrolled environment.

5.2 Applicable Measurement Standards

IEEE 1528–2013: Recommended Practice for Determining the Peak Spatial-Average Specific Absorption Rate (SAR) in the Human Head from Wireless Communications Devices: Measurement Techniques.

KDB447498 D01 General RF Exposure Guidance v06: Mobile and Portable Devices RF Exposure Procedures and Equipment Authorization Policies.

KDB648474 D04 Handset SAR v01r03: SAR Evaluation Considerations for Wireless Handsets.

KDB941225 D01 SAR test for 3G devices v03r01: SAR Measurement Procedures for 3G Devices

KDB941225 D05 SAR for LTE Devices v02r05: SAR Evaluation Considerations for LTE Devices

KDB941225 D06 Hotspot Mode SAR v02r01: SAR Evaluation Procedures for Portable Devices with Wireless Router Capabilities

KDB248227 D01 802.11 Wi-Fi SAR v02r02: SAR GUIDANCE FOR IEEE 802.11 (Wi-Fi) TRANSMITTERS

KDB865664 D01SAR measurement 100 MHz to 6 GHz v01r04: SAR Measurement Requirements for 100 MHz to 6 GHz.

KDB865664 D02 RF Exposure Reporting v01r02: RF Exposure Compliance Reporting and Documentation Considerations



6 Specific Absorption Rate (SAR)

6.1 Introduction

SAR is related to the rate at which energy is absorbed per unit mass in an object exposed to a radio field. The SAR distribution in a biological body is complicated and is usually carried out by experimental techniques or numerical modeling. The standard recommends limits for two tiers of groups, occupational/controlled and general population/uncontrolled, based on a person's awareness and ability to exercise control over his or her exposure. In general, occupational/controlled exposure limits are higher than the limits for general population/uncontrolled.

6.2 SAR Definition

The SAR definition is the time derivative (rate) of the incremental energy (dW) absorbed by (dissipated in) an incremental mass (dm) contained in a volume element (dv) of a given density (ρ). The equation description is as below:

$$SAR = \frac{d}{dt}(\frac{dW}{dm}) = \frac{d}{dt}(\frac{dW}{\rho dv})$$

SAR is expressed in units of Watts per kilogram (W/kg)

SAR measurement can be either related to the temperature elevation in tissue by

$$SAR = c(\frac{\delta T}{\delta t})$$

Where: C is the specific head capacity, δT is the temperature rise and δt is the exposure duration, or related to the electrical field in the tissue by

$$SAR = \frac{\sigma |E|^2}{\rho}$$

Where: σ is the conductivity of the tissue, ρ is the mass density of tissue and E is the RMS electrical field strength.

However for evaluating SAR of low power transmitter, electrical field measurement is typically applied.



7 Tissue Simulating Liquids

7.1 Targets for tissue simulating liquid

Table 7.1: Targets for tissue simulating liquid

				<u> </u>			
Frequency(MHz)	Liquid Type	Conductivity(σ)	± 5% Range	Permittivity(ε)	± 5% Range		
835	Head	0.90	0.86~0.95	41.5	39.4~43.6		
835	Body	0.97	0.92~1.02	55.2	52.4~58.0		
1900	Head	1.40	1.33~1.47	40.0	38.0~42.0		
1900	Body	1.52	1.44~1.60	53.3	50.6~56.0		
2450	Head	1.80	1.71~1.89	39.2	37.2~41.2		
2450	Body	1.95	1.85~2.05	52.7	50.1~55.3		
2600	Head	1.96	1.86~2.06	39.01	37.06~40.96		
2600	Body	2.16	2.05~2.27	52.5	49.9~55.1		
5250	Head	4.71	4.47~4.95	35.93	34.1~37.7		
5250	Body	5.36	5.09~5.63	48.9	46.5~51.3		
5600	Head	5.07	4.82~5.32	35.53	33.8~37.3		
5600	Body	5.77	5.48~6.06	48.5	46.1~50.9		
5750	Head	5.22	4.96~5.48	35.36	33.6~37.1		
5750	Body	5.94	5.64~6.24	48.3	45.9~50.7		

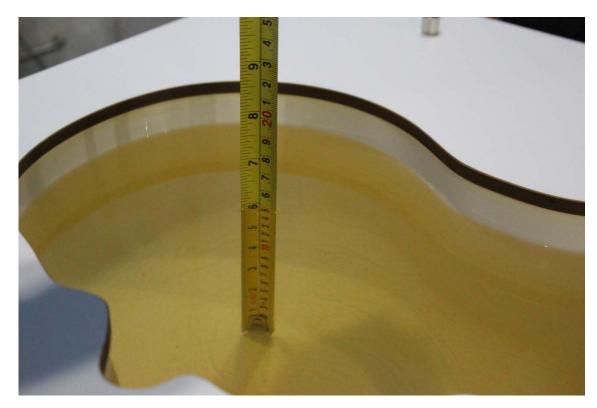
7.2 Dielectric Performance

Table 7.2: Dielectric Performance of Tissue Simulating Liquid

Measurement Date yyyy/mm/dd	Frequency	Туре	Permittivity ε	Drift (%)	Conductivity σ (S/m)	Drift (%)
2017/12/25	750 MHz	Head	42.73	1.88	0.879	-1.24
2017/12/25	730 IVITZ	Body	56.1	1.08	0.96	0.00
2017/12/26	OOE MIL	Head	42.3	1.93	0.892	-0.89
2017/12/26	835 MHz	Body	54.72	-0.87	0.954	-1.65
2017/12/27	1750 MHz	Head	40.25	0.42	1.388	1.31
2017/12/27		Body	52.74	-1.24	1.493	0.20
2017/12/28	1900 MHz	Head	39.8	-0.50	1.398	-0.14
2017/12/20	1900 MIDZ	Body	52.53	-1.44	1.492	-1.84
2017/12/20	2450 MH=	Head	39.15	-0.13	1.823	1.28
2017/12/29	2450 MHz	Body	53.48	1.48	1.927	-1.18
2017/12/20	2600 MH=	Head	38.56	-1.15	1.95	-0.51
2017/12/30	2600 MHz	Body	51.9	-1.14	2.145	-0.69

Note: The liquid temperature is $22.3^{\circ}\mathrm{C}$



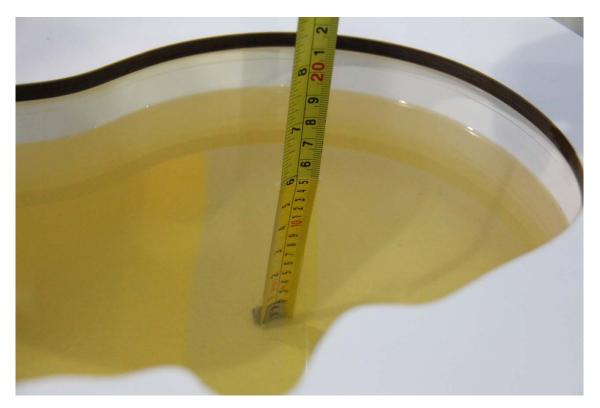


Picture 7-1 Liquid depth in the Head Phantom (750 MHz)



Picture 7-2 Liquid depth in the Flat Phantom (750 MHz)





Picture 7-3 Liquid depth in the Head Phantom (835MHz)

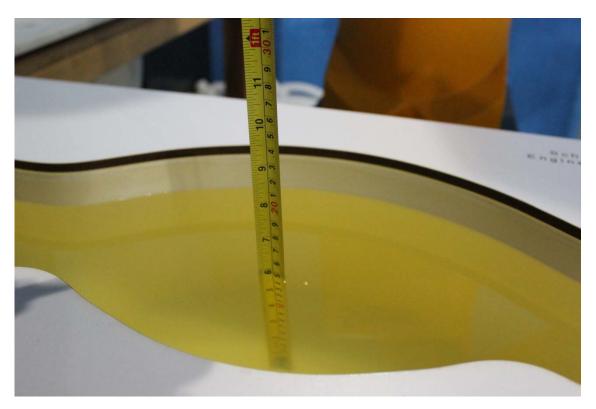


Picture 7-4 Liquid depth in the Flat Phantom (835MHz)





Picture 7-5 Liquid depth in the Head Phantom (1750 MHz)

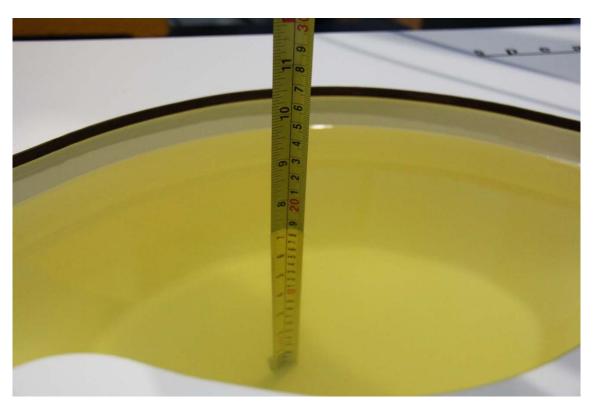


Picture 7-6 Liquid depth in the Flat Phantom (1750MHz)





Picture 7-7 Liquid depth in the Head Phantom (1900 MHz)

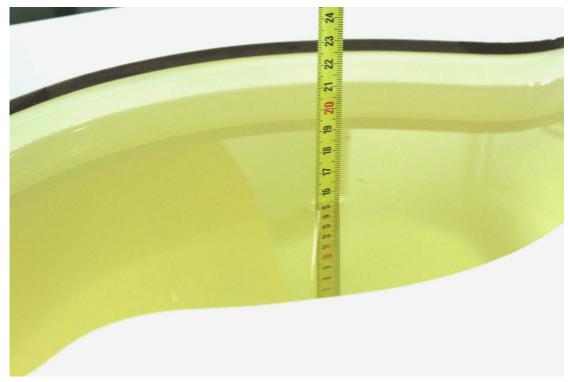


Picture 7-8 Liquid depth in the Flat Phantom (1900MHz)





Picture 7-9 Liquid depth in the Head Phantom (2450MHz)



Picture 7-10 Liquid depth in the Flat Phantom (2450MHz)





Picture 7-11 Liquid depth in the Head Phantom (2600 MHz Head)



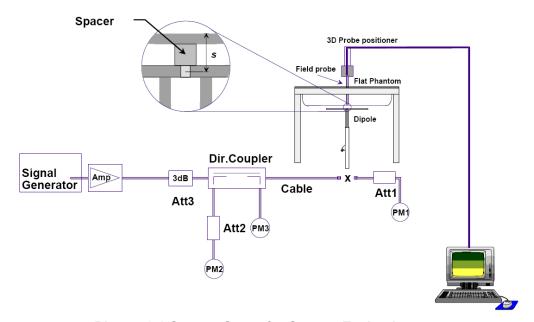
Picture 7-12 Liquid depth in the Flat Phantom (2600MHz)



8 System verification

8.1 System Setup

In the simplified setup for system evaluation, the DUT is replaced by a calibrated dipole and the power source is replaced by a continuous wave that comes from a signal generator. The calibrated dipole must be placed beneath the flat phantom section of the SAM twin phantom with the correct distance holder. The distance holder should touch the phantom surface with a light pressure at the reference marking and be oriented parallel to the long side of the phantom. The equipment setup is shown below:



Picture 8.1 System Setup for System Evaluation



Picture 8.2 Photo of Dipole Setup



8.2 System Verification

SAR system verification is required to confirm measurement accuracy, according to the tissue dielectric media, probe calibration points and other system operating parameters required for measuring the SAR of a test device. The system verification must be performed for each frequency band and within the valid range of each probe calibration point required for testing the device.

The system verification results are required that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR. The details are presented in annex B.

Table 8.1: System Verification of Head

Measurement Date	Measurement Date Frequency		Target value (W/kg)		ed value kg)	Deviation		
(yyyy-mm- dd)	rrequency	10 g Average	1 g Average	10 g Average	1 g Average	10 g Average	1 g Average	
2017/12/25	750 MHz	5.42	8.32	5.4	8.4	-0.37%	0.96%	
2017/12/26	835 MHz	6.06	9.37	6	9.4	-0.99%	0.32%	
2017/12/27	1750 MHz	19.4	36.7	19.24	36.72	-0.82%	0.05%	
2017/12/28	1900 MHz	21.0	40.0	20.6	40.32	-1.90%	0.80%	
2017/12/29	2450 MHz	24.7	52.2	24.28	52.64	-1.70%	0.84%	
2017/12/30	2600 MHz	25.8	57.9	25.6	57.68	-0.78%	-0.38%	

Table 8.2: System Verification of Body

Measurement Date		Target value (W/kg)			ed value kg)	Deviation		
(yyyy-mm- dd)	Frequency	10 g Average	1 g Average	10 g Average	1 g Average	10 g Average	1 g Average	
2017/12/25	750 MHz	5.68	8.66	5.72	8.6	0.70%	-0.69%	
2017/12/26	835 MHz	6.12	9.41	6.04	9.24	-1.31%	-1.81%	
2017/12/27	1750 MHz	19.8	37.1	19.72	37.2	-0.40%	0.27%	
2017/12/28	1900 MHz	21.5	40.5	21.84	40.04	1.58%	-1.14%	
2017/12/29	2450 MHz	23.8	50.4	23.6	49.92	-0.84%	-0.95%	
2017/12/30	2600 MHz	24.8	55.5	25.12	55.68	1.29%	0.32%	



9 Measurement Procedures

9.1 Tests to be performed

In order to determine the highest value of the peak spatial-average SAR of a handset, all device positions, configurations and operational modes shall be tested for each frequency band according to steps 1 to 3 below. A flowchart of the test process is shown in picture 9.1.

Step 1: The tests described in 9.2 shall be performed at the channel that is closest to the center of the transmit frequency band (f_c) for:

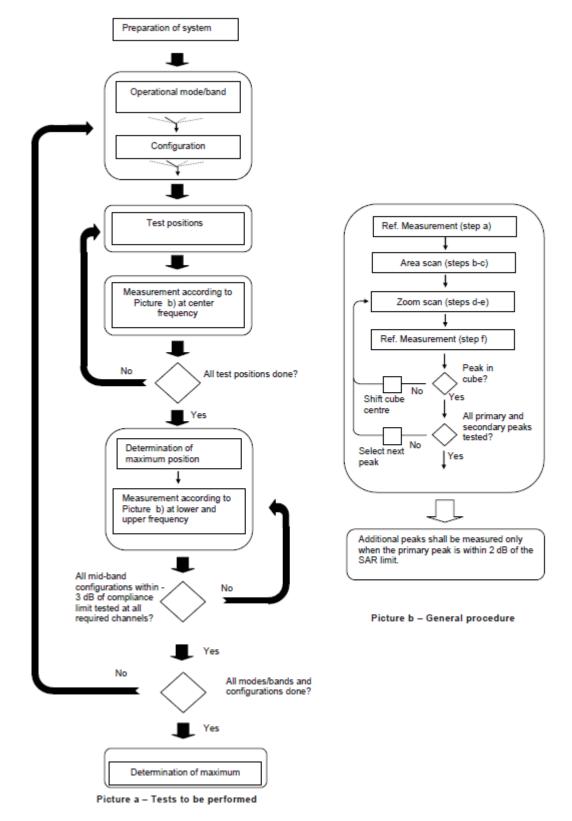
- a) all device positions (cheek and tilt, for both left and right sides of the SAM phantom, as described in annex D),
- b) all configurations for each device position in a), e.g., antenna extended and retracted, and c) all operational modes, e.g., analogue and digital, for each device position in a) and configuration in b) in each frequency band.

If more than three frequencies need to be tested according to 11.1 (i.e., $N_c >$ 3), then all frequencies, configurations and modes shall be tested for all of the above test conditions.

Step 2: For the condition providing highest peak spatial-average SAR determined in Step 1, perform all tests described in 9.2 at all other test frequencies, i.e., lowest and highest frequencies. In addition, for all other conditions (device position, configuration and operational mode) where the peak spatial-average SAR value determined in Step 1 is within 3 dB of the applicable SAR limit, it is recommended that all other test frequencies shall be tested as well.

Step 3: Examine all data to determine the highest value of the peak spatial-average SAR found in Steps 1 to 2.





Picture 9.1 Block diagram of the tests to be performed



9.2 General Measurement Procedure

The area and zoom scan resolutions specified in the table below must be applied to the SAR measurements and fully documented in SAR reports to qualify for TCB approval. Probe boundary effect error compensation is required for measurements with the probe tip closer than half a probe tip diameter to the phantom surface. Both the probe tip diameter and sensor offset distance must satisfy measurement protocols; to ensure probe boundary effect errors are minimized and the higher fields closest to the phantom surface can be correctly measured and extrapolated to the phantom surface for computing 1-g SAR. Tolerances of the post-processing algorithms must be verified by the test laboratory for the scan resolutions used in the SAR measurements, according to the reference distribution functions specified in IEEE Std 1528-2013. The results should be documented as part of the system validation records and may be requested to support test results when all the measurement parameters in the following table are not satisfied.

			≤ 3 GHz	> 3 GHz	
Maximum distance from (geometric center of pro			5 ± 1 mm	½-5-ln(2) ± 0.5 mm	
Maximum probe angle f normal at the measurem		axis to phantom surface	30°±1°	20° ± 1°	
			\leq 2 GHz: \leq 15 mm 2 - 3 GHz: \leq 12 mm	$3-4 \text{ GHz} \le 12 \text{ mm}$ $4-6 \text{ GHz} \le 10 \text{ mm}$	
Maximum area scan spatial resolution: Δx_{Area} , Δy_{Area}			When the x or y dimension of the test device, in the measurement plane orientation, is smaller than the above, th measurement resolution must be ≤ the corresponding x or y dimension of the test device with at least one measurement point on the test device.		
Maximum zoom scan sp	atial resolu	tion: Δx_{Zoom} , Δy_{Zoom}	≤ 2 GHz: ≤ 8 mm 2 – 3 GHz: ≤ 5 mm*	3 – 4 GHz: ≤ 5 mm* 4 – 6 GHz: ≤ 4 mm*	
	uniform g	zrid: Δz _{Zoom} (n)	3 - 4 GHz: ≤ ≤ 5 mm 4 - 5 GHz: ≤ 5 - 6 GHz: ≤		
Maximum zoom scan spatial resolution, normal to phantom surface	graded	Δz _{Zoom} (1): between 1 st two points closest to phantom surface	≤ 4 mm	3 – 4 GHz: ≤ 3 mm 4 – 5 GHz: ≤ 2.5 mm 5 – 6 GHz: ≤ 2 mm	
surface	grid Δz _{Zoom} (n>1): between subsequent points		$\leq 1.5 \cdot \Delta z_{Zoom}(n-1)$		
Minimum zoom scan volume x, y, z		≥ 30 mm	3 – 4 GHz: ≥ 28 mm 4 – 5 GHz: ≥ 25 mm 5 – 6 GHz: ≥ 22 mm		

Note: 5 is the penetration depth of a plane-wave at normal incidence to the tissue medium; see draft standard IEEE P1528-2011 for details.

When zoom scan is required and the <u>reported</u> SAR from the area scan based *I-g SAR estimation* procedures of KDB 447498 is ≤ 1.4 W/kg, ≤ 8 mm, ≤ 7 mm and ≤ 5 mm zoom scan resolution may be applied, respectively, for 2 GHz to 3 GHz, 3 GHz to 4 GHz and 4 GHz to 6 GHz.



9.3 WCDMA Measurement Procedures for SAR

The following procedures are applicable to WCDMA handsets operating under 3GPP Release99, Release 5 and Release 6. The default test configuration is to measure SAR with an established radio link between the DUT and a communication test set using a 12.2kbps RMC (reference measurement channel) configured in Test Loop Mode 1. SAR is selectively confirmed for other physical channel configurations (DPCCH & DPDCHn), HSDPA and HSPA (HSUPA/HSDPA) modes according to output power, exposure conditions and device operating capabilities. Both uplink and downlink should be configured with the same RMC or AMR, when required. SAR for Release 5 HSDPA and Release 6 HSPA are measured using the applicable FRC (fixed reference channel) and E-DCH reference channel configurations. Maximum output power is verified according to applicable versions of 3GPP TS 34.121 and SAR must be measured according to these maximum output conditions. When Maximum Power Reduction (MPR) is not implemented according to Cubic Metric (CM) requirements for Release 6 HSPA, the following procedures do not apply.

For Release 5 HSDPA Data Devices:

Sub-test	$oldsymbol{eta_c}$	$oldsymbol{eta_{\!d}}$	β_d (SF)	eta_c / eta_d	$oldsymbol{eta_{hs}}$	CM/dB
1	2/15	15/15	64	2/15	4/15	0.0
2	12/15	15/15	64	12/15	24/25	1.0
3	15/15	8/15	64	15/8	30/15	1.5
4	15/15	4/15	64	15/4	30/15	1.5

For Release 6 HSPA Data Devices

Sub-	$oldsymbol{eta_{\!c}}$	$eta_{\!\scriptscriptstyle d}$	$oldsymbol{eta_d}$ (SF)	eta_c / eta_d	$eta_{\scriptscriptstyle hs}$	$oldsymbol{eta_{ec}}$	$oldsymbol{eta}_{ed}$	$oldsymbol{eta_{ed}}$	eta_{ed}	CM (dB)	MPR (dB)	AG Index	E- TFCI
1	11/15	15/15	64	11/15	22/15	209/225	1039/225	4	1	1.5	1.5	20	75
2	6/15	15/15	64	6/15	12/15	12/15	12/15	4	1	1.5	1.5	12	67
3	15/15	9/15	64	15/9	30/15	30/15	$eta_{ed1:47/15} \ eta_{ed2:47/15}$	4	2	1.5	1.5	15	92
4	2/15	15/15	64	2/15	4/15	4/15	56/75	4	1	1.5	1.5	17	71
5	15/15	15/15	64	15/15	24/15	30/15	134/15	4	1	1.5	1.5	21	81

Rel.8 DC-HSDPA (Cat 24)

SAR test exclusion for Rel.8 DC-HSDPA must satisfy the SAR test exclusion requirements of Rel.5 HSDPA. SAR test exclusion for DC-HSDPA devices is determined by power measurements according to the H-Set 12, Fixed Reference Channel (FRC) configuration in Table C.8.1.12 of 3GPP TS 34.121-1. A primary and a secondary serving HS-DSCH Cell are required to perform the power measurement and for the results to qualify for SAR test exclusion.



9.4 SAR Measurement for LTE

SAR tests for LTE are performed with a base station simulator, Rohde & Rchwarz CMW500. Closed loop power control was used so the UE transmits with maximum output power during SAR testing. All powers were measured with the CMW 500.

It is performed for conducted power and SAR based on the KDB941225 D05.

SAR is evaluated separately according to the following procedures for the different test positions in each exposure condition – head, body, body-worn accessories and other use conditions. The procedures in the following subsections are applied separately to test each LTE frequency band.

- 1) QPSK with 1 RB allocation
 - Start with the largest channel bandwidth and measure SAR for QPSK with 1 RB allocation, using the RB offset and required test channel combination with the highest maximum output power among RB offsets at the upper edge, middle and lower edge of each required test channel. When the reported SAR is ≤ 0.8 W/kg, testing of the remaining RB offset configurations and required test channels is not required for 1 RB allocation; otherwise, SAR is required for the remaining required test channels and only for the RB offset configuration with the highest output power for that channel. When the reported SAR of a required test channel is > 1.45 W/kg, SAR is required for all three RB offset configurations for that required test channel.
- 2) QPSK with 50% RB allocation The procedures required for 1 RB allocation in 1) are applied to measure the SAR for QPSK with 50% RB allocation.
- 3) QPSK with 100% RB allocation
 - For QPSK with 100% RB allocation, SAR is not required when the highest maximum output power for 100 % RB allocation is less than the highest maximum output power in 50% and 1 RB allocations and the highest reported SAR for 1 RB and 50% RB allocation in 1) and 2) are \leq 0.8 W/kg. Otherwise, SAR is measured for the highest output power channel; and if the reported SAR is > 1.45 W/kg, the remaining required test channels must also be tested.

9.5 Bluetooth & Wi-Fi Measurement Procedures for SAR

Normal network operating configurations are not suitable for measuring the SAR of 802.11 transmitters in general. Unpredictable fluctuations in network traffic and antenna diversity conditions can introduce undesirable variations in SAR results. The SAR for these devices should be measured using chipset based test mode software to ensure that the results are consistent and reliable.

Chipset based test mode software is hardware dependent and generally varies among manufacturers. The device operating parameters established in a test mode for SAR measurements must be identical to those programmed in production units, including output power levels, amplifier gain settings and other RF performance tuning parameters. The test frequencies should correspond to actual channel frequencies defined for domestic use. SAR for devices with switched diversity should be measured with only one antenna transmitting at a time during each SAR measurement, according to a fixed modulation and data rate. The same data pattern should be used for all measurements.



9.6 Power Drift

To control the output power stability during the SAR test, DASY4 system calculates the power drift by measuring the E-field at the same location at the beginning and at the end of the measurement for each test position. These drift values can be found in section 14 labeled as: (Power Drift [dB]). This ensures that the power drift during one measurement is within 5%.

10 Area Scan Based 1-g SAR

10.1 Requirement of KDB

According to the KDB447498 D01 v05, when the implementation is based the specific polynomial fit

algorithm as presented at the 29th Bioelectromagnetics Society meeting (2007) and the estimated 1-g SAR is \leq 1.2 W/kg, a zoom scan measurement is not required provided it is also not needed for any other purpose; for example, if the peak SAR location required for simultaneous transmission SAR test exclusion can be determined accurately by the SAR system or manually to discriminate between distinctive peaks and scattered noisy SAR distributions from area scans.

There must not be any warning or alert messages due to various measurement concerns identified by the SAR system; for example, noise in measurements, peaks too close to scan boundary, peaks are too sharp, spatial resolution and uncertainty issues etc. The SAR system verification must also demonstrate that the area scan estimated 1-g SAR is within 3% of the zoom scan 1-g SAR (See Annex B). When all the SAR results for each exposure condition in a frequency band and wireless mode are based on estimated 1-g SAR, the 1-g SAR for the highest SAR configuration must be determined by a zoom scan.

10.2 Fast SAR Algorithms

The approach is based on the area scan measurement applying a frequency dependent attenuation parameter. This attenuation parameter was empirically determined by analyzing a large number of phones. The MOTOROLA FAST SAR was developed and validated by the MOTOROLA Research Group in Ft. Lauderdale.

In the initial study, an approximation algorithm based on Linear fit was developed. The accuracy of the algorithm has been demonstrated across a broad frequency range (136-2450 MHz) and for both 1- and 10-g averaged SAR using a sample of 264 SAR measurements from 55 wireless handsets. For the sample size studied, the root-mean-squared errors of the algorithm are 1.2% and 5.8% for 1- and 10-g averaged SAR, respectively. The paper describing the algorithm in detail is expected to be published in August 2004 within the Special Issue of Transactions on MTT.

In the second step, the same research group optimized the fitting algorithm to an Polynomial fit whereby the frequency validity was extended to cover the range 30-6000MHz. Details of this study can be found in the BEMS 2007 Proceedings.

Both algorithms are implemented in DASY software.



11 Conducted Output Power

11.1 GSM Measurement result

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured peak output power should be greater and within 5% than EMI measurement.

GSM850 #1 Measured Power (dBm) Frame Burst Power (dBm) Caculation CH251 CH190 CH128 CH251 CH190 Config Tune-up 848.8 MHz | 836.6 MHz | 824.2 MHz 848.8 MHz | 836.6 MHz | 824.2 MHz **GSM Speech** 33 50 32.63 32.61 32.52 **GPRS 1 Txslot** -9.03 23.56 23.51 23.41 32 59 32 54 32 44 33.50 **GPRS 2 Txslots** 32.00 31.89 31.82 31.73 -6 02 25.87 25 80 25.71 **GPRS 3 Txslots** 30.50 30.14 30.05 29.95 -4.2625.88 25.79 25.69 **GPRS 4 Txslots** 29.00 -3.01 25.96 25.85 28.97 28.97 28.86 EGPRS GMSK 1 Txslot 33.50 32.52 32.48 32.93 -9.03 23.49 23.45 23.90 **EGPRS GMSK 2 Txslots** 32.00 31.83 31.79 -6.02 25.81 25.77 25.83 31.85 **EGPRS GMSK 3 Txslots** 30.50 30.09 30.02 30.08 -4.2625.83 25.76 25 82 **EGPRS GMSK 4 Txslots** 25.91 29.00 28.92 28.94 -3.01 25.93 25.95 28.96 EGPRS 8PSK 1 Txslot 28.00 27.08 -9.03 18.05 27.23 27.09 18.20 18.06 20.20 **EGPRS 8PSK 2 Txslots** 26.50 26.20 26.22 26.10 -6.0220.18 20.08 **EGPRS 8PSK 3 Txslots** 25.00 24.38 24.35 24.29 -4.2620.12 20.09 20.03 **EGPRS 8PSK 4 Txslots** 23,50 23.25 23.22 23.24 -3.01 20.24 20.21 20.23

Table 11-1 GSM850 #1

Table 11-2 PCS1900 #1

			PCS19	00 #1					
		Measu	red Power	(dBm)		Frame Burst Power		(dBm)	
Config	Tune-up	CH810 1909.8 MHz	CH661 1880 MHz	CH512 1850.2 MHz	Caculation	CH810 1909.8 MHz	CH661 1880 MHz	CH512 1850.2 MHz	
GSM Speech	30.50	29.43	29.41	29.34					
GPRS 1 Txslot	31.00	29.43	29.40	29.33	-9.03	20.40	20.37	20.30	
GPRS 2 Txslots	29.50	28.72	28.69	28.62	-6.02	22.70	22.67	22.60	
GPRS 3 Txslots	28.00	27.00	26.95	26.88	-4.26	22.74	22.69	22.62	
GPRS 4 Txslots	26.50	25.88	25.85	25.77	-3.01	22.87	22.84	22.76	
EGPRS GMSK 1 Txslot	31.00	29.34	29.38	29.32	-9.03	20.31	20.35	20.29	
EGPRS GMSK 2 Txslots	29.50	28.63	28.67	28.60	-6.02	22.61	22.65	22.58	
EGPRS GMSK 3 Txslots	28.00	26.91	26.93	26.86	-4.26	22.65	22.67	22.60	
EGPRS GMSK 4 Txslots	26.50	25.79	25.84	25.76	-3.01	22.78	22.83	22.75	
EGPRS 8PSK 1 Txslot	27.00	26.36	26.55	26.82	-9.03	17.33	17.52	17.79	
EGPRS 8PSK 2 Txslots	26.00	25.39	25.56	25.89	-6.02	19.37	19.54	19.87	
EGPRS 8PSK 3 Txslots	24.00	23.34	23.53	23.55	-4.26	19.08	19.27	19.29	
EGPRS 8PSK 4 Txslots	23.00	22.31	22.50	22.82	-3.01	19.30	19.49	19.81	

NOTES:

Division Factors

To average the power, the division factor is as follows:

1TX-slot = 1 transmit time slot out of 8 time slots=> conducted power divided by (8/1) => -9.03dB

2TX-slots = 2 transmit time slots out of 8 time slots=> conducted power divided by (8/2) => -6.02dB

3TX-slots = 3 transmit time slots out of 8 time slots=> conducted power divided by (8/3) => -4.26dB

4TX-slots = 4 transmit time slots out of 8 time slots=> conducted power divided by (8/4) => -3.01dB

According to the conducted power as above, the body measurements are performed with 4Txslots for 850MHz and 1900MHz.



11.2 WCDMA Measurement result

	WCDMA1900-BII #1									
			Measi	Measured Power (dBm)						
Item	Tuna un	CH9538	CH9400	CH9262						
item		Tune-up	1907.6 MHz	1880 MHz	1852.4 MHz					
WCDMA	RMC	24.00	23.45	23.60	23.67					
	subtest1	21.00	20.14	20.32	20.50					
	subtest2	21.00	20.12	20.31	20.50					
HSUPA	subtest3	22.00	21.15	21.35	21.50					
	subtest4	20.00	19.74	19.89	19.99					
	subtest5	21.50	20.99	21.22	21.43					
HSPA+	1	22.00	21.71	21.74	21.77					
	subtest1	23.00	22.26	22.28	22.36					
DC-HSDPA	subtest2	23.00	22.28	22.29	22.30					
DC-U2DPA	subtest3	23.00	22.27	22.31	22.28					
	subtest4	23.00	22.24	22.26	22.32					

	WCD	MA1700-BIV	#1			
			Measured Power (dBm)			
ltam	Item		CH1513	CH1412	CH1312	
iteiii			1752.6 MHz	1732.4 MHz	1712.4 MHz	
WCDMA	RMC	24.00	23.72	23.69	23.61	
	subtest1	21.00	20.78	20.69	20.61	
	subtest2	21.00	20.78	20.68	20.61	
HSUPA	subtest3	22.00	21.79	21.67	21.67	
	subtest4	20.50	20.29	20.22	20.16	
	subtest5	22.00	21.70	21.63	21.56	
HSPA+	١	22.00	21.99	21.94	21.93	
	subtest1	23.00	22.49	22.45	22.47	
DC-HSDPA	subtest2	23.00	22.51	22.44	22.46	
рс-порга	subtest3	23.00	22.48	22.45	22.47	
	subtest4	23.00	22.52	22.49	22.47	

	WCE	MA850-BV#	#1		
			Meas	ured Power	(dBm)
Item		Tune un	CH4233	CH4182	CH4132
item		Tune-up	846.6 MHz	835.4 MHz	826.4 MHz
WCDMA	RMC	24.00	23.78	23.76	23.85
	subtest1	21.00	20.67	20.76	20.76
	subtest2	21.00	20.64	20.71	20.75
HSUPA	subtest3	22.00	21.65	21.78	21.77
	subtest4	20.50	20.14	20.28	20.26
	subtest5	22.00	21.58	21.68	21.74
HSPA+	1	22.00	21.70	21.75	21.68
	subtest1	23.00	22.23	22.24	22.19
DC-HSDPA	subtest2	23.00	22.25	22.27	22.22
DC-113DPA	subtest3	23.00	22.24	22.26	22.23
	subtest4	23.00	22.23	22.28	22.21



11.3 LTE Measurement result

Table 11-3 LTE1900-FDD2 #1

l			1900-FDD2 #		asured Pow	er (dBm) & MF	PR
			I	QP	SK	16Q	AM
BandWidth	RB No./Start	Channel	Tune-up	Measured Power	MPR	Measured Power	MPF
		19193	24.5	23.73	0	22.49	1
	1H	18900	24.5	24.44	0	22.68	1
		18607	24.5	24.03	0	23.11	1
		19193	24.5	23.97	0	22.68	1
	1M	18900	24.5	23.87	0	22.82	1
		18607	24.5	23.96	0	23.25	1
		19193	24.5	23.76	0	22.51	1
	1L	18900	24.5	23.72	0	22.65	1
		18607	24.5	23.82	0	23.08	1
		19193	24.5	23.62	0	22.72	1
1.4MHz	3H	18900	24.5	23.72	0	22.68	1
		18607	24.5	23.87	0	23.03	1
	555.65	19193	24.5	23.66	0	22.74	1
	3M	18900	24.5	23.78	0	22.69	1
		18607	24.5	23.93	0	23.05	1
		19193	24.5	23.65	0	22.69	1
	3L	18900	24.5	23.73	0	22.68	1
		18607	24.5	23.93	0	22.99	1
		19193	24.5	22.67	1	21.70	2
	6	18900	24.5	22.70	1	21.72	2
		18607	24.5	22.84	1	21.93	2
						22.55	
		19185	24.5	23.94	0	22.53	1
	1H	18900	24.5	23.88	0	22.56	1
		18615	24.5	23.97	0	23.21	1
	1M	19185	24.5	23.88	0	22.68	1
		18900	24.5	23.86	0	22.66	1
		18615	24.5	23.93	0	23.35	1
		19185	24.5	23.63	0	22.60	1
	1L	18900	24.5	23.86	0	22.58	1
		18615	24.5	23.96	0	23.19	1
		19185	24.5	22.78	1	21.74	2
3MHz	8H	18900	24.5	22.85	1	21.90	2
		18615	24.5	22.93	1	21.99	2
	l l	19185	24.5	22.80	1	21.80	2
	8M	18900	24.5	22.82	1	21.91	2
		18615	24.5	22.87	1	22.07	2
	0	19185	24.5	22.79	1	21.78	2
	8L	18900 18615	24.5	22.84 22.88	1	21.92	2
			24.5		1	22.04	2
	15	19185 18900	24.5 24.5	22.69 22.74	1	21.69	2
	15				1	21.81	
	+ -	18615	24.5	22.87		21.98	2
	+ -	19175	24.5	23.70	0	22.62	1
	111		24.5	23.70	0	22.62	1
	1H	18900	24.5	23.68	0	22.75	1
	\vdash	18625 19175	24.5 24.5	23.85	0	23.27	1
	1M	18900	24.5	23.93 23.90	0	22.84	1
		18625	24.5	24.08	0	23.49	1
		19175	24.5	23.75	0	22.64	1
	1L	18900	24.5	23.69	0	22.73	1
	"	18625	24.5	23.87	0	23.27	1
		19175	24.5	22.62	1	21.70	2
5MHz	12H	18900	24.5	22.67	1	21.82	2
J	'2''	18625	24.5	22.85	1	22.09	2
		19175	24.5	22.76	1	21.81	2
	12M	18900	24.5	22.73	1	21.84	2
	12101	18625	24.5	22.73	1	22.11	2
		19175	24.5	22.70	1	21.76	2
	12L	18900	24.5	22.73	1	21.76	2
	126	18625	24.5	22.73	1	22.08	2
		19175	24.5	22.61	1	21.64	2
		10110	24.0	22.01		21.04	
	25	18900	24.5	22.69	1	21.78	2



					ı		
		19150	24.5	23.86	0	22.87	1
	1H	18900	24.5	23.82	0	22.63	1
	I	18650	24.5	24.00	0	22.67	1
		19150	24.5	24.00	0	23.04	1
	1M	18900	24.5	24.01	0	22.70	1
		18650	24.5	24.12	0	22.85	1
		19150	24.5	23.83	0	22.86	1
	1L	18900	24.5	23.89	0	22.63	1
	"	18650	24.5	23.96	0	22.75	1
					1		2
10MHz	2511	19150	24.5	22.67	1	21.68	2
IOIVINZ	25H	18900	24.5	22.69	1	21.85	2
		18650	24.5	22.94	_	22.05	2
	25M	19150	24.5	22.69	1		2
	ZSIVI	18900	24.5			21.94	
		18650	24.5	22.89	1	22.02	2
	251	19150	24.5	22.75	1	21.75	2
	25L	18900	24.5	22.81	1	21.92	2
		18650	24.5	22.95	1	22.06	2
	-	19150	24.5	22.63	1	21.65	2
	50	18900	24.5	22.75	1	21.84	2
		18650	24.5	22.95	1	22.01	2
		19125	24.5	23.68	0	22.36	1
	1H	18900	24.5	23.65	0	22.85	1
		18675	24.5	23.80	0	22.87	1
		19125	24.5	23.84	0	22.43	1
	1M	18900	24.5	23.86	0	23.01	1
		18675	24.5	23.98	0	23.21	1
		19125	24.5	23.74	0	22.42	1
	1L	18900	24.5	23.90	0	22.91	1
		18675	24.5	23.85	0	23.12	1
		19125	24.5	22.86	1	21.82	2
15MHz	36H	18900	24.5	22.82	1	21.88	2
		18675	24.5	23.05	1	22.05	2
		19125	24.5	22.88	1	21.83	2
	36M	18900	24.5	22.91	1	21.97	2
		18675	24.5	23.03	1	22.02	2
		19125	24.5	22.88	1	21.82	2
	36L	18900	24.5	22.96	1	21.98	2
		18675	24.5	22.99	1	21.99	2
		19125	24.5	22.86	1	21.76	2
	75	18900	24.5	22.88	1	21.87	2
		18675	24.5	23.06	1	22.05	2
		19100	24.5	23.41	0	22.67	1
	1H	18900	24.5	23.40	0	22.72	1
	1	18700	24.5	23.54	0	22.87	1
		19100	24.5	23.93	0	23.06	1
	1M	18900	24.5	23.93	0	23.14	1
	1	18700	24.5	24.03	0	23.49	1
		19100	24.5	23.48	0	22.85	1
	1L	18900	24.5	23.63	0	22.73	1
	"-	18700	24.5	23.63	0	23.13	1
		19100	24.5	22.56	1	21.56	2
20MHz	50H	18900	24.5	22.61	1	21.62	2
		18700	24.5	22.79	1	21.83	2
		19100	24.5	22.62	1	21.66	2
	50M	18900	24.5	22.73	1	21.76	2
	30101	18700	24.5	22.73	1	21.76	2
	—				1		
	50L	19100 18900	24.5	22.67 22.78	1	21.72 21.78	2
	SUL		24.5		1		
		18700	24.5	22.85		21.93	2
	1	19100	24.5	22.62	1	21.63	2
	400	40000	04.5	00 70			
	100	18900 18700	24.5 24.5	22.70 22.83	1	21.76 21.94	2



Table 11-4 LTE1700-FDD4 #1

SN .			1700-FDD4 #		asured Pow	ver (dBm) & MF	PR
			Г	QP		16Q	
BandWidth	RB No./Start	Channel	Tune-up	Measured		Measured	
				Power	MPR	Power	MPR
		20393	24	23.38	0	22.29	1
	1H	20175	24	23.34	0	22.21	1
	"	19957	24	23.38	0	22.60	1
		20393	24	23.67	0	22.47	1
	1M	20175	24	23.51	0	22.42	1
	''''	19957	24	23.61	0	22.84	1
		20393	24	23.40	0	22.29	1
	1L	20175	24	23.31	0	22.21	1
	"	19957	24	23.44	0	22.68	1
		20393	24	23.43	0	22.48	1
1.4MHz	3H	20175	24	23.30	0	22.24	1
1.411112	311	19957	24	23.46	0	22.62	1
		20393	24	23.45	0	22.56	1
	зм	20175	24	23.34	0	22.29	1
	Sivi	19957	24	23.52	0	22.64	1
		20393			0		1
	l a l		24	23.39		22.49	
	3L	20175	24	23.27	0	22.22	1
		19957	24	23.48		_	1
		20393	24	22.39	1	21.48	2
	6	20175	24	22.27	1	21.19	2
		19957	24	22.47	1	21.61	2
					-	1	
	l l	20385	24	23.33	0	22.17	1
	1H	20175	24	23.25	0	21.98	1
		19965	24	23.33	0	22.55	1
		20385	24	23.57	0	22.34	1
	1M	20175	24	23.26	0	22.14	1
		19965	24	23.35	0	22.38	1
		20385	24	23.37	0	22.24	1
	1L	20175	24	23.24	0	22.01	1
		19965	24	23.40	0	22.65	1
		20385	24	22.39	1	21.43	2
3MHz	8H	20175	24	22.20	1	21.33	2
		19965	24	22.32	1	21.40	2
		20385	24	22.44	1	21.45	2
	8M	20175	24	22.25	1	21.36	2
	1 1	19965	24	22.35	1	21.50	2
		20385	24	22.42	1	21.43	2
	8L	20175	24	22.23	1	21.34	2
	1 1	19965	24	22.33	1	21.48	2
		20385	24	22.34	1	21.31	2
	15	20175	24	22.16	1	21.23	2
		19965	24	22.25	1	21.37	2
			1				
		20375	24	23.34	0	22.26	1
	1H	20175	24	23.23	0	22.19	1
		19975	24	23.16	0	22.58	1
		20375	24	23.61	0	22.49	1
	1M	20175	24	23.28	0	22.04	1
	''''	19975	24	23.29	0	22.89	1
		20375	24	23.34	0	22.22	1
	1L	20375	24	23.22	0	22.15	1
	'-	19975	24	23.27	0	22.67	1
		20375	24	22.34	1	21.40	2
5MHz	12H	20375	24	22.34	1	21.40	2
JIVII 1Z	120	19975	24	22.15	1	21.43	2
	\vdash			-		_	2
	4014	20375	24	22.40	1	21.50	
	12M	20175	24	22.20	1	21.34	2
	\vdash	19975	24	22.29	11	21.52	2
		20375	24	22.33	1	21.40	2
	12L	20175	24	22.14	11	21.27	2
		19975	24	22.23	1	21.43	2
	η Τ	20375	24	22.33	1	21.31	2
	25	20175	24	22.12	1	21.21	2
	1 [19975	24	22.25	1	21.34	2



		20350	24	23.34	0	22.18	1
	1H	20350	24	23.34	0		1
	I "	20000	24	23.23	0	22.01 22.45	1
		20350	24	23.40	0	22.23	1
	1M	20350	24	23.34	0	22.23	1
	1101	20000	24	23.40	0	22.59	1
					_		_
	- 11	20350	24	23.28	0	22.17	1
	1L	20175	24	23.18	0	21.96	_
		20000	24	23.31	0	22.57	1
10141	2511	20350	24	22.31	1	21.42	2
10MHz	25H	20175	24	22.19	1	21.25	2
		20000	24	22.24	1	21.33	2
	2514	20350	24	22.31	1	21.46	2
	25M	20175	24	22.17	1	21.24	2
		20000	24	22.26	1	21.35	2
	051	20350	24	22.34	1	21.44	2
	25L	20175	24	22.15	1	21.21	2
		20000	24	22.29	1	21.39	2
	1.20	20350	24	22.29	1	21.36	2
	50	20175	24	22.12	1	21.15	2
		20000	24	22.24	1	21.32	2
	No. Company	20325	24	23.35	0	22.43	1
	1H	20175	24	23.11	0	21.95	1
		20025	24	23.09	0	22.28	1
		20325	24	23.44	0	22.59	1
	1M	20175	24	23.26	0	22.02	1
		20025	24	23.29	0	22.52	1
		20325	24	23.24	0	22.43	1
	1L	20175	24	23.13	0	21.90	1
		20025	24	23.28	0	22.53	1
		20325	24	22.45	1	21.39	2
15MHz	36H	20175	24	22.32	1	21.33	2
		20025	24	22.34	1	21.42	2
		20325	24	22.43	1	21.42	2
	36M	20175	24	22.33	1	21.31	2
	11112	20025	24	22.36	1	21.43	2
		20325	24	22.43	1	21.43	2
	36L	20175	24	22.29	1	21.30	2
		20025	24	22.34	1	21.40	2
		20325	24	22.48	1	21.46	2
	75	20175	24	22.33	1	21.28	2
		20025	24	22.40	1	21.38	2
		20300	24	23.11	0	22.28	1
	1H	20175	24	22.92	0	22.35	1
		20050	24	22.88	0	22.14	1
		20300	24	23.48	0	22.71	1
	1M	20175	24	23.38	0	22.79	1
		20050	24	23.40	0	22.66	1
		20300	24	22.99	0	22.22	1
	1L	20175	24	22.95	0	22.34	1
	"	20050	24	23.00	0	22.39	1
		20300	24	22.17	1	21.21	2
20MHz	50H	20175	24	22.09	1	21.17	2
ZOIVII IZ	3011	20050	24	22.12	1	21.17	2
		20300	24	22.12	1	21.29	2
	50M	20300	24	22.29	1	21.29	2
	SUIVI				1	21.25	2
		20050	24	22.20			
	501	20300	24	22.26	1	21.25	2
	50L	20175	24	22.09	1	21.16	2
		20050	24	22.21	1	21.24	2
	400	20300	24	22.24	1	21.29	2
	100	20175	24	22.06 22.16	1	21.15 21.21	2
		20050	24				



Table 11-5 LTE850-FDD5 #1

		LTE	850-FDD5#	1			
						er (dBm) & M	
					SK		AM
BandWidth	RB No./Start	Channel	Tune-up	Measured Power	MPR	Measured Power	MPR
	1	20643	23	22.62	0	21.70	1
	1H	20525	23	22.70	0	21.88	1
		20407	23	22.88	0	21.96	1
		20643	23	22.84	0	21.83	1
	1M	20525	23	22.89	0	21.96	1
		20407	23	22.96	0	21.99	1
		20643	23	22.60	0	21.66	1
	1L	20525	23	22.73	0	21.88	1
		20407	23	22.88	0	21.97	1
	1 1	20643	23	22.78	0	21.92	1
1.4MHz	3H	20525	23	22.78	0	21.95	1
		20407	23	22.94	0	21.99	1
		20643	23	22.80	0	21.92	1
	3M	20525	23	22.83	0	21.99	1
		20407	23	22.98	0	21.99	1
	l	20643	23	22.75	0	21.97	1
	3L	20525	23	22.76	0	21.94	1
		20407	23	22.94	0	21.99	1
		20643	23	21.72	1	20.96	2
	6	20525	23	21.79	1	20.94	2
	+	20407	23	21.94	1	20.90	2
	+	00000		00.77		04 =:	
		20635	23	22.65	0	21.71	1
	1H	20525	23	22.74	0	21.73	1
	\vdash	20415	23	22.94	0	21.98	1
		20635	23	22.81	0	21.85	1
	1M	20525	23	22.91	0	21.83	1
		20415	23	22.95	0	21.95	1
	4.	20635	23	22.74	0	21.76	1
	1L	20525	23	22.74	0	21.68	1
		20415	23	22.95	0	21.96	1
3MHz	8Н	20635 20525	23 23	21.81 21.80	1	20.77	2
SIVINZ	•п	20325	23	21.00	1	21.00	2
	\vdash	20635	23	21.86	1	20.85	2
	8M	20525	23	21.89	1	20.95	2
	OIVI	20325	23	21.92	1	20.98	2
		20635	23	21.81	1	20.80	2
	8L	20525	23	21.88	1	20.96	2
		20415	23	21.99	1	20.97	2
		20635	23	21.81	1	20.72	2
	15	20525	23	21.88	1	20.88	2
		20415	23	21.97	1	20.98	2
	1						
	1	20625	23	22.66	0	21.73	1
	1H	20525	23	22.68	0	21.85	1
		20425	23	22.76	0	21.98	1
		20625	23	22.90	0	21.95	1
	1M	20525	23	23.00	0	21.99	1
		20425	23	22.98	0	21.98	1
		20625	23	22.66	0	21.76	1
	1L	20525	23	22.77	0	21.89	1
		20425	23	22.77	0	21.99	1
		20625	23	21.71	1	20.79	2
5MHz	12H	20525	23	21.79	1	20.89	2
		20425	23	21.88	1	20.98	2
		20625	23	21.79	1	20.86	2
	12M	20525	23	21.85	1	20.98	2
		20425	23	21.96	1	20.96	2
		20625	23	21.75	1	20.79	2
	12L	20525	23	21.82	1	20.91	2
		20425	23	21.86	1	20.99	2
		20625	23	21.74	1	20.67	2
		COESE	22	21.84	1	20.87	2
	25	20525 20425	23	21.04	1	20.98	2



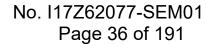


			I	I			
		20600	23	22.66	0	21.72	1
	1H	20525	23	22.66	0	21.66	1
		20450	23	22.84	0	21.99	1
		20600	23	22.76	0	21.82	1
	1M	20525	23	22.86	0	21.79	1
		20450	23	23.00	0	21.99	1
		20600	23	22.66	0	21.83	1
	1L	20525	23	22.82	0	21.70	1
		20450	23	22.93	0	21.98	1
		20600	23	21.76	1	20.82	2
10MHz	25H	20525	23	21.83	1	20.91	2
		20450	23	21.89	1	20.92	2
		20600	23	21.85	1	20.93	2
	25M	20525	23	21.90	1	20.94	2
		20450	23	21.95	1	20.97	2
		20600	23	21.85	1	20.95	2
	25L	20525	23	21.92	1	20.96	2
		20450	23	21.92	1	20.94	2
		20600	23	21.81	1	20.81	2
	50	20525	23	21.88	1	20.87	2
		20450	23	21.92	1	20.91	2



Table 11-6 LTE2500-FDD7 #1

		LTE	2500-FDD7 #				
						er (dBm) & M	
			l _		SK		AM
BandWidth	RB No./Start	Channel	Tune-up	Measured Power	MPR	Measured Power	MPR
		21425	24	22.97	0	21.79	1
	1H	21100	24	23.23	0	22.13	1
		20775	24	23.52	0	22.79	1
		21425	24	23.18	0	22.08	1
	1M	21100	24	23.51	0	22.44	1
		20775	24	23.80	0	22.95	1
		21425	24	22.99	0	21.86	1
	1L	21100	24	23.32	0	22.20	1
		20775	24	23.61	0	22.83	1
5.41		21425	24	21.93	1	20.90	2
5MHz	12H	21100	24	22.21	1	21.20	2
		20775	24	22.57	1	21.61	2
	1204	21425	24	21.98 22.27	1	20.98	2
	12M	21100 20775	24 24	22.60	1	21.27 21.65	2
		21425	24	21.94	1	20.89	2
	12L	21100	24	22.22	1	21.22	2
	126	20775	24	22.54	1	21.22	2
	\vdash	21425	24	21.94	1	20.81	2
	25	21100	24	22.18	1	21.10	2
	25	20775	24	22.18	1	21.10	2
	+	20110		22.02	'	21.40	
	+	21400	24	22.96	0	21.70	1
	1H	21100	24	23.20	0	21.88	1
		20800	24	23.58	0	22.71	1
		21400	24	23.09	0	21.90	1
	1M	21100	24	23.46	0	22.15	1
		20800	24	23.74	0	22.86	1
		21400	24	23.03	0	21.86	1
	1L	21100	24	23.31	0	22.04	1
		20800	24	23.70	0	22.75	1
		21400	24	21.95	1	20.96	2
10MHz	25H	21100	24	22.25	1	21.15	2
		20800	24	22.55	1	21.53	2
		21400	24	21.93	1	20.97	2
	25M	21100	24	22.24	1	21.21	2
		20800	24	22.56	1	21.46	2
		21400	24	21.97	1	20.98	2
	25L	21100	24	22.24	1	21.20	2
		20800	24	22.55	1	21.48	2
		21400	24	21.94	1	20.92	2
	50	21100	24	22.24	1	21.17	2
		20800	24	22.55	1	21.49	2
		21375	24	23.02	0	21.96	1
	1H	21100	24	23.08	0	21.81	1
		20825	24	23.43	0	22.65	1
		21375	24	23.16	0	22.13	1
	1M	21100	24	23.34	0	22.04	1
		20825	24	23.63	0	22.77	1
	, MARINE	21375	24	23.16	0	22.15	1
	1L	21100	24	23.28	0	22.04	1
		20825	24	23.65	0	22.73	1
45 CA 10 CA	01823141 MX	21375	24	22.15	1	20.97	2
15MHz	36H	21100	24	22.40	1	21.25	2
		20825	24	22.70	1	21.70	2
	100000	21375	24	22.12	1	20.99	2
	36M	21100	24	22.43	1	21.30	2
		20825	24	22.74	1	21.65	2
		21375	24	22.18	1	21.01	2
	36L	21100	24	22.46	1	21.27	2
		20825	24	22.74	1	21.62	2
	-20	21375	24	22.15	1	21.00	2
	75	21100	24	22.45	1	21.29	2
		20825	24	22.72	1	21.60	2





		21350	24	22.73	0	21.88	1
	1H	21100	24	22.88	0	22.02	1
		20850	24	23.16	0	22.60	1
		21350	24	23.23	0	22.29	1
	1M	21100	24	23.45	0	22.57	1
		20850	24	23.73	0	22.98	1
		21350	24	22.95	0	22.04	1
	1L	21100	24	23.16	0	22.40	1
		20850	24	23.42	0	22.74	1
		21350	24	21.92	1	20.91	2
20MHz	50H	21100	24	22.14	1	21.10	2
		20850	24	22.52	1	21.52	2
		21350	24	21.97	1	20.88	2
	50M	21100	24	22.23	1	21.15	2
		20850	24	22.54	1	21.48	2
		21350	24	22.00	1	20.96	2
	50L	21100	24	22.21	1	21.13	2
		20850	24	22.48	1	21.43	2
		21350	24	21.99	1	20.93	2
	100	21100	24	22.24	1	21.17	2
		20850	24	22.50	1	21.48	2



Table 11-7 LTE700-FDD12 #1

		LTE	700-FDD12 #				
						er (dBm) & Mi	
			l	QP	SK	16Q	AM
BandWidth	RB No./Start	Channel	Tune-up	Measured Power	MPR	Measured Power	MPR
		23173	23	22.74	0	21.77	1
	1H	23095	23	22.77	0	21.81	1
	1 1	23017	23	22.68	0	21.98	1
		23173	23	22.95	0	21.91	1
	1M	23095	23	22.89	0	21.91	1
		23017	23	22.90	0	21.99	1
		23173	23	22.71	0	21.72	1
	1L	23095	23	22.78	0	21.83	1
	'-	23017	23	22.71	0	21.98	1
		23173	23	22.89	0	21.95	1
1.4MHz	3H	23095	23	22.87	0	21.91	1
		23017	23	22.79	0	21.98	1
		23173	23	22.92	0	21.96	1
	3М	23095	23	22.87	0	21.94	1
	"	23017	23	22.84	0	21.96	1
		23173	23	22.90	0	21.98	1
	3L	23095	23	22.92	0	21.94	1
	"	23093	23	22.78	0	21.95	1
	\vdash	23173	23	21.86	1	20.96	2
	6	23095	23	21.88	1	20.95	2
	"	23095	23	21.88	1	20.95	2
		23017	23	21.77		20.96	
	_	00405		20.00		04.70	-
	4	23165	23	22.80	0	21.73	11
	1H	23095	23	22.81	0	21.63	1
		23025	23	22.79	0	21.85	1
		23165	23	22.91	0	21.86	1
	1M	23095	23	22.76	0	21.74	1
		23025	23	22.87	0	21.88	1
		23165	23	22.82	0	21.84	1
	1L	23095	23	22.70	0	21.66	1
		23025	23	22.73	0	21.96	1
		23165	23	21.82	1	20.83	2
3MHz	8H	23095	23	21.74	1	20.85	2
		23025	23	21.72	1	20.77	2
		23165	23	21.87	1	20.91	2
	8M	23095	23	21.73	1	20.90	2
	1 1	23025	23	21.73	1	20.83	2
		23165	23	21.85	1	20.90	2
	8L	23095	23	21.78	1	20.87	2
		23025	23	21.69	1	20.79	2
		23165	23	21.81	1	20.80	2
	15	23095	23	21.77	1	20.84	2
	"	23025	23	21.69	1	20.73	2
	 			,	-		
	+ +	23155	23	22.81	0	21.79	1
	1H	23095	23	22.78	0	21.87	1
	"'	23035	23	22.78	0	21.95	1
	\vdash	23155	23	22.02	0	21.95	1
	1M	23155	23	22.98	0		1
	IIVI					21.92	
	\vdash	23035	23	22.87	0	21.99	1
	41	23155	23	22.79	0	21.80	1
	1L	23095	23	22.75	0	21.81	1
	\vdash	23035	23	22.59	0	21.96	1
EN 41 1-	40	23155	23	21.77	1	20.87	2
5MHz	12H	23095	23	21.74	1	20.84	2
		23035	23	21.74	1	20.92	2
	Vice to	23155	23	21.84	1	20.91	2
	12M	23095	23	21.78	1	20.87	2
		23035	23	21.75	1	20.93	2
		23155	23	21.76	1	20.86	2
	12L	23095	23	21.77	1	20.89	2
		23035	23	21.58	1	20.81	2
		23155	23	21.79	1	20.77	2
	25	23095	23	21.78	1	20.81	2





		23130	23	22.81	0	21.79	1
	1H	23095	23	22.75	0	21.67	1
		23060	23	22.82	0	21.96	1
		23130	23	22.82	0	21.87	1
	1M	23095	23	22.85	0	21.73	1
		23060	23	22.79	0	21.98	1
		23130	23	22.70	0	21.75	1
	1L	23095	23	22.67	0	21.57	1
		23060	23	22.71	0	21.65	1
		23130	23	21.85	1	20.96	2
10MHz	25H	23095	23	21.86	1	20.88	2
		23060	23	21.72	1	20.77	2
		23130	23	21.88	1	20.98	2
	25M	23095	23	21.81	1	20.85	2
		23060	23	21.76	1	20.83	2
		23130	23	21.84	1	20.96	2
	25L	23095	23	21.85	1	20.91	2
		23060	23	21.66	1	20.72	2
		23130	23	21.89	1	20.91	2
	50	23095	23	21.84	1	20.85	2
		23060	23	21.72	1	20.75	2



Table 11-8 LTE750-FDD13 #1

		TABLE TI-6	750-FDD13			<u> </u>	
		LIL	100 1 0 0 10 1		asured Pow	er(dBm)&MP	R
				QPS		16Q A	
BandW idth	RB No./S tart	C hannel	Tune-up	M easured Power	MPR	M easured Power	M PR
		23255	24	23.12	0	22.17	1
	1H	23230	24	23.19	0	22.22	1
		23205	24	23.11	0	22.68	1
		23255	24	23.34	0	22.40	1
	1 M	23230	24	23.43	0	22.54	1
		23205	24	23.34	0	22.92	1
		23255	24	23.17	0	22.22	1
	1L	23230	24	23.17	0	22.34	1
		23205	24	23.10	0	22.65	1
		23255	24	22.28	1	21.30	2
5M H z	12Н	23230	24	22.24	1	21.33	2
		23205	24	22.17	1	21.34	2
		23255	24	22.26	1	21.33	2
	12M	23230	24	22.29	1	21.43	2
		23205	24	22.31	1	21.45	2
		23255	24	22.20	1	21.26	2
	12L	23230	24	22.26	1	21.40	2
		23205	24	22.30	1	21.44	2
		23255	24	22.22	1	21.18	2
	25	23230	24	22.29	1	21.33	2
		23205	24	22.29	1	21.31	2
		Н	/	/	0	/	1
	1H	M	/	/	0	/	1
		23230	24	23.20	0	22.50	1
		Н	/	/	0	/	1
	1 M	M	/	/	0	/	1
		23230	24	23.31	0	22.72	1
		Н	/	/	0	/	1
	1L	M	/	/	0	/	1
		23230	24	23.21	0	22.53	1
		Н	/	/	1	/	2
10M H z	25Н	M	/	/	1	/	2
		23230	24	22.42	1	21.41	2
		Н	/	/	1	/	2
	25M	M	/	/	1	/	2
		23230	24	22.37	1	21.40	2
		Н	/	/	1	/	2
	25L	M	/	/	1	/	2
		23230	24	22.41	1	21.48	2
		Н	/	/	1	/	2
	50	M	/	/	1	/	2
		23230	24	22.43	1	21.46	2



11.4 Wi-Fi and BT Measurement result

The output power of BT antenna is as following:

Table 11-9 Bluetooth Power

Bluetooth Power				
Mode	Channel	Frequence	Tune-up	Measured
GFSK	78	2480 MHz	6.5	5.08
	39	2441 MHz	6.5	6.19
	0	2402 MHz	6.5	5.29
EDR2M-4_DQPSK	78	2480 MHz	5.5	4.01
	39	2441 MHz	5.5	5.03
	0	2402 MHz	5.5	4.16
EDR3M-8DPSK	78	2480 MHz	5	3.96
	39	2441 MHz	5	4.9
	0	2402 MHz	5	4.22

The average conducted power for Wi-Fi is as following: